



ZHT431

#### Description

The ZHT431 is a three terminal adjustable shunt regulator offering excellent temperature stability and output current handling capability up to 100mA. The device offers extended operating temperature range working from -55 to +125°C.

The output voltage may be set to any chosen voltage between 2.5 and 20 volts by selection of two external divider resistors.

The devices can be used as a replacement for zener diodes in many applications requiring an improvement in zener performance.

#### Features

- Surface Mount SOT23 (Type DN) Package
- 0.5%, 1% and 2% Tolerance
- Maximum Temperature Coefficient 67ppm/°C
- Temperature Compensated for Operation Over the Full
  Temperature Range
- Programmable Output Voltage
- 50µA to 100mA Current Sink Capability
- Low Output Noise
- Wide Temperature Range -55 to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## Pin Assignments



ADJUSTABLE PRECISION ZENER SHUNT REGULATOR

### Applications

- Series and Shunt Regulator
- Voltage Monitor
- Over Voltage / Under Voltage Protection
- Switch Mode Power Supplies

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen, Antimony and Beryllium-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl), <1000ppm antimony compounds and <1000ppm Beryllium.

## **Typical Application Circuit**





### Absolute Maximum Ratings (Voltages to GND Unless Otherwise Stated.)

Parameter	Rating	Unit
Cathode Voltage (Vz)	20	V
Cathode Current	150	mA
Operating Temperature	-55 to +125	C
Storage Temperature	-55 to +150	C°
Power Dissipation (T <sub>A</sub> = +25°C, T <sub>JMAX</sub> = +150°C)	330	mW

### **Recommended Operating Conditions**

Parameter	Min	Мах	Unit
Cathode Voltage V <sub>REF</sub>		20	V
Cathode Current	0.05	100	mA

#### **Electrical Characteristics** (Test conditions unless otherwise specified: T<sub>A</sub> = +25°C.)

Querte al Normania		Values				
Symbol	VParameter	Min.	Тур.	Max.	Unit	Conditions
V <sub>REF</sub>	Reference Voltage 2%	2.45	2.50	2.55		I <sub>L</sub> = 10mA (Fig.1),
· KEI	1%	2.475	2.50	2.525	V	$V_z = V_{REF}$
	0.5%	2.4875	2.50	2.5125		VZ = VREF
V <sub>DEV</sub>	Deviation of Reference Input Voltage Over Temperature		10	30	mV	$I_L = 10mA, V_Z = V_{REF}$ T <sub>A</sub> = Full Range (Fig.1)
ΔV <sub>REF</sub>	Ratio of the Change in Reference Voltage to		-1.85	-2.7	mV/V	$V_Z$ from $V_{REF}$ to 10V I <sub>Z</sub> = 10mA (Fig.2)
ΔVz the Change in Cathode Voltage	the Change in Cathode Voltage	_	-1.0	-2.0	mV/V	$V_Z$ from 10V to 20V I <sub>Z</sub> = 10mA (Fig.2)
I <sub>REF</sub>	Reference Input Current		0.12	1.0	μA	R1 = 10k, R2 = O/C, I <sub>L</sub> = 10mA (Fig.2)
$\Delta I_{REF}$	EF Deviation of Reference Input Current Over Temperature		0.04	0.2	μA	R1 = 10k, R2 = O/C, $I_L$ =10mA, $T_A$ = Full Range (Fig.2)
I <sub>ZMIN</sub>	N Minimum Cathode Current for Regulation		35	50	μA	V <sub>Z</sub> = V <sub>REF</sub> (Fig.1)
IZOFF	F Off-state Current		_	0.1	μA	$V_Z = 20V, V_{REF} = 0V$ (Fig.3)
Rz	Dynamic Output Impedance		_	0.75	V	$V_Z = V_{REF}$ (Fig.1), f = 0Hz, I <sub>C</sub> = 1mA to 100mA

Deviation of reference input voltage,  $V_{DEV}$ , is defined as the maximum variation of the reference input voltage over the full temperature range. The average temperature coefficient of the reference input voltage,  $V_{REF}$  is defined as:

$$V_{REF}\left(\frac{ppm}{\circ C}\right) = \frac{V_{DEV} \times 100000}{V_{REF}(T1 - T2)}$$

The dynamic output impedance,  $\mathsf{R}_{\mathsf{Z}},$  is defined as:

$$R_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R1 and R2, (Fig. 2), the dynamic output impedance of the overall circuit, R', is defined as:

$$R' = R_Z(1 + \frac{R1}{R2})$$

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# **Typical Operating Conditions**



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# Typical Operating Conditions (Cont.)



Frequency (Hz)

#### Gain v Frequency











### Test Circuit for Open Loop Voltage Gain





Test Circuit for Pulse Response



 $V_{REF} < V_Z < 20V, Iz = 10mA, T_A = 25^{\circ}C$ 

Test Circuit for Stability Boundary Conditions



# **DC Test Circuits**







Fig 3 - Test circuit for Off state current<sup>†</sup>



Fig 2 - Test circuit for  $V_Z > V_{ref}$ 

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## **Application Circuits**





Output control of a three terminal fixed regulator



Single supply comparator with temperature compensated threshold









Over voltage / under voltage protection circuit



## Ordering Information



Part Number	Tolerance (%)	Package (Note 5)	Part Mark	Reel Size (inches)	Quantity per reel	Tape Width	Status (Note 4)
ZHT431F01TA	1	SOT23 (Type DN)	43C	7	3000	8mm	In Production
ZHT431F01-7	1	SOT23 (Type DN)	43C	7	3000	8mm	End of Life
ZHT431FMTA	0.5	SOT23 (Type DN)	43P	7	3000	8mm	In Production
ZHT431F02TA	2	SOT23 (Type DN)	43D	7	3000	8mm	In Production

Notes: 4. ZHT431F01-7 is End of Life without any alternative.

5. For packaging details, go to our website at: https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

#### SOT23 (Type DN)



XXX : Part Mark



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for latest version.

#### (1) Package Type: SOT23 (Type DN)



SOT23 (Type DN)					
Dim	Min	Max	Тур		
Α	0.89	1.12	1.00		
A1	0.01	0.10	0.05		
b	0.30	0.51	0.45		
c	0.08	0.20	0.10		
D	2.80	3.04	3.00		
ш	2.10	2.64	2.42		
E1	1.20	1.40	1.37		
е	0.95 REF				
e1	1.90 REF				
L	0.25	0.60	0.30		
L1	0.45	0.62	0.54		
All Dimensions in mm					

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for latest version.

#### (1) Package Type: SOT23 (Type DN)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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